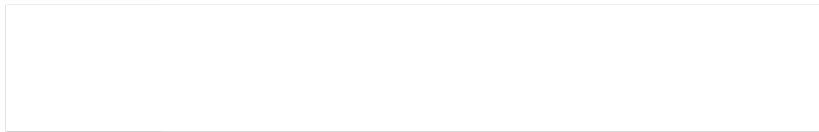


Thyristor Module



Phase leg

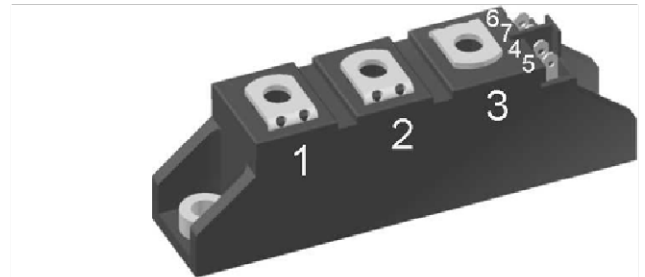
$$V_{RRM} = 2 \times 1600 \text{ V}$$

$$I_{TAV} = 49 \text{ A}$$

$$V_T = 1.34 \text{ V}$$

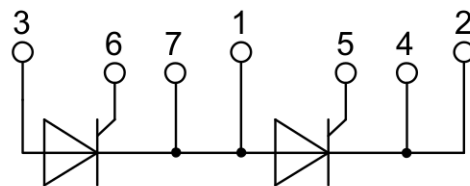
Part number

MCC44-16io1B



Backside: isolated

 E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al₂O₃-ceramic

Applications:

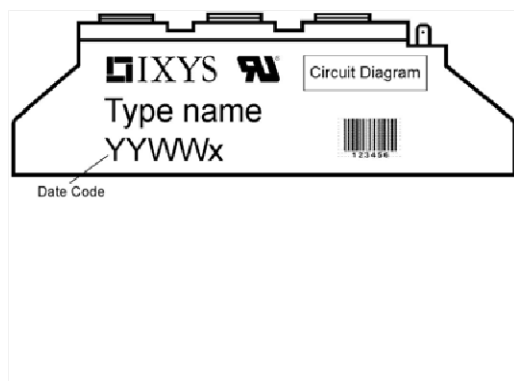
- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Thyristor				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM/DSM}	max. non-repetitive reverse/forward blocking voltage	T _{VJ} = 25°C				1700	V
V _{RRM/DRM}	max. repetitive reverse/forward blocking voltage	T _{VJ} = 25°C				1600	V
I _{R/D}	reverse current, drain current	V _{R/D} = 1600 V	T _{VJ} = 25°C			100	μA
		V _{R/D} = 1600 V	T _{VJ} = 125°C			5	mA
V _T	forward voltage drop	I _T = 100 A	T _{VJ} = 25°C			1.34	V
		I _T = 200 A				1.75	V
		I _T = 100 A	T _{VJ} = 125°C			1.34	V
		I _T = 200 A				1.80	V
I _{TAV}	average forward current	T _C = 85°C	T _{VJ} = 125°C			49	A
I _{T(RMS)}	RMS forward current	180° sine				77	A
V _{T0}	threshold voltage	} for power loss calculation only		T _{VJ} = 125°C		0.85	V
r _T	slope resistance					5.3	mΩ
R _{thJC}	thermal resistance junction to case					0.53	K/W
R _{thCH}	thermal resistance case to heatsink				0.20		K/W
P _{tot}	total power dissipation	T _C = 25°C				180	W
I _{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	T _{VJ} = 45°C			1.15	kA
		t = 8,3 ms; (60 Hz), sine	V _R = 0 V			1.24	kA
		t = 10 ms; (50 Hz), sine	T _{VJ} = 125°C			980	A
		t = 8,3 ms; (60 Hz), sine	V _R = 0 V			1.06	kA
I ² t	value for fusing	t = 10 ms; (50 Hz), sine	T _{VJ} = 45°C			6.62	kA²s
		t = 8,3 ms; (60 Hz), sine	V _R = 0 V			6.40	kA²s
		t = 10 ms; (50 Hz), sine	T _{VJ} = 125°C			4.80	kA²s
		t = 8,3 ms; (60 Hz), sine	V _R = 0 V			4.63	kA²s
C _J	junction capacitance	V _R = 400 V f = 1 MHz	T _{VJ} = 25°C		54		pF
P _{GM}	max. gate power dissipation	t _p = 30 μs	T _C = 125°C			10	W
		t _p = 300 μs				5	W
P _{GAV}	average gate power dissipation					0.5	W
(di/dt) _{cr}	critical rate of rise of current	T _{VJ} = 125°C; f = 50 Hz	repetitive, I _T = 150 A			150	A/μs
		t _p = 200 μs; di _G /dt = 0.45 A/μs;					
		I _G = 0.45A; V _D = ⅔ V _{DRM}	non-repet., I _T = 49 A			500	A/μs
(dv/dt) _{cr}	critical rate of rise of voltage	V _D = ⅔ V _{DRM}	T _{VJ} = 125°C			1000	V/μs
		R _{GK} = ∞; method 1 (linear voltage rise)					
V _{GT}	gate trigger voltage	V _D = 6 V	T _{VJ} = 25°C			1.5	V
			T _{VJ} = -40°C			1.6	V
I _{GT}	gate trigger current	V _D = 6 V	T _{VJ} = 25°C			100	mA
			T _{VJ} = -40°C			200	mA
V _{GD}	gate non-trigger voltage	V _D = ⅔ V _{DRM}	T _{VJ} = 125°C			0.2	V
I _{GD}	gate non-trigger current					10	mA
I _L	latching current	t _p = 10 μs	T _{VJ} = 25°C			450	mA
		I _G = 0.45A; di _G /dt = 0.45 A/μs					
I _H	holding current	V _D = 6 V R _{GK} = ∞	T _{VJ} = 25°C			200	mA
t _{gd}	gate controlled delay time	V _D = ½ V _{DRM}	T _{VJ} = 25°C			2	μs
		I _G = 0.45A; di _G /dt = 0.45 A/μs					
t _q	turn-off time	V _R = 100 V; I _T = 120 A; V _D = ⅔ V _{DRM}	T _{VJ} = 125°C		150		μs
		di/dt = 10 A/μs; dv/dt = 20 V/μs; t _p = 200 μs					

Package TO-240AA				Ratings			Unit
Symbol	Definition	Conditions		min.	typ.	max.	
I_{RMS}	RMS current	per terminal				200	A
T_{VJ}	virtual junction temperature			-40		125	°C
T_{op}	operation temperature			-40		100	°C
T_{stg}	storage temperature			-40		125	°C
Weight					90		g
M_D	mounting torque			2.5		4	Nm
M_T	terminal torque			2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	13.0	9.7			mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0			mm
V_{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3600			V
		t = 1 minute		3000			V



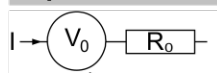
Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC44-16io1B	MCC44-16io1B	Box	6	452920

Similar Part	Package	Voltage class
MCMA50P1600TA	TO-240AA-1B	1600
MCMA65P1600TA	TO-240AA-1B	1600

Equivalent Circuits for Simulation

* on die level

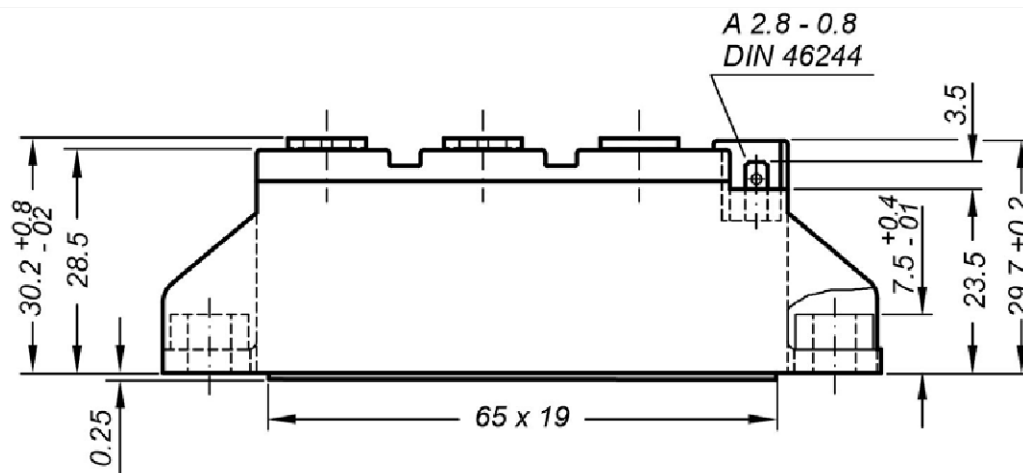
$T_{VJ} = 125$ °C



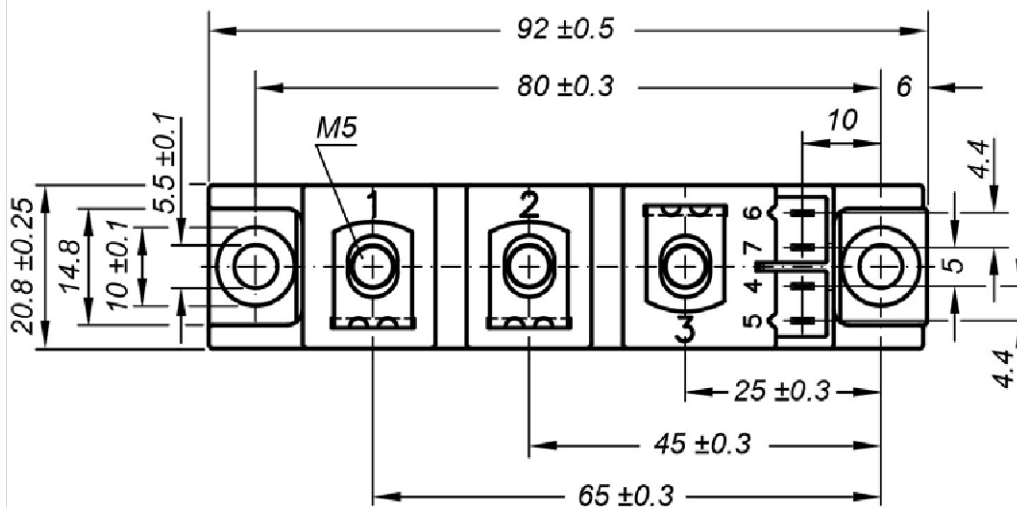
Thyristor

$V_{0 \max}$	threshold voltage	0.85	V
$R_{0 \max}$	slope resistance *	4.1	mΩ

Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c“



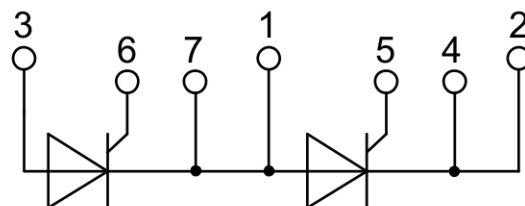
Optional accessories: Keyed gate/cathode twin plugs

Wire length: 350 mm, gate = white, cathode = red

UL 758, style 3751

Type **ZY 200L** (L = Left for pin pair 4/5)

Type **ZY 200R** (R = Right for pin pair 6/7)



Thyristor

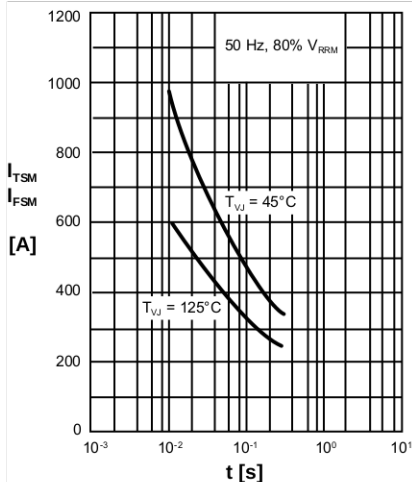


Fig. 1 Surge overload current
 I_{TSM} , I_{FSM} : Crest value, t : duration

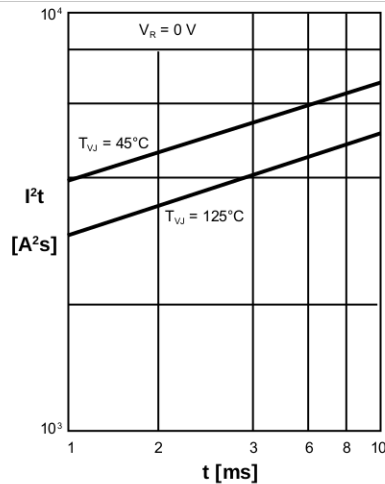


Fig. 2 I^2t versus time (1-10 ms)

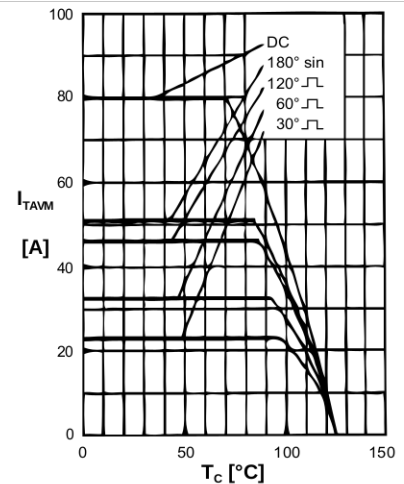


Fig. 3 Maximum forward current at case temperature

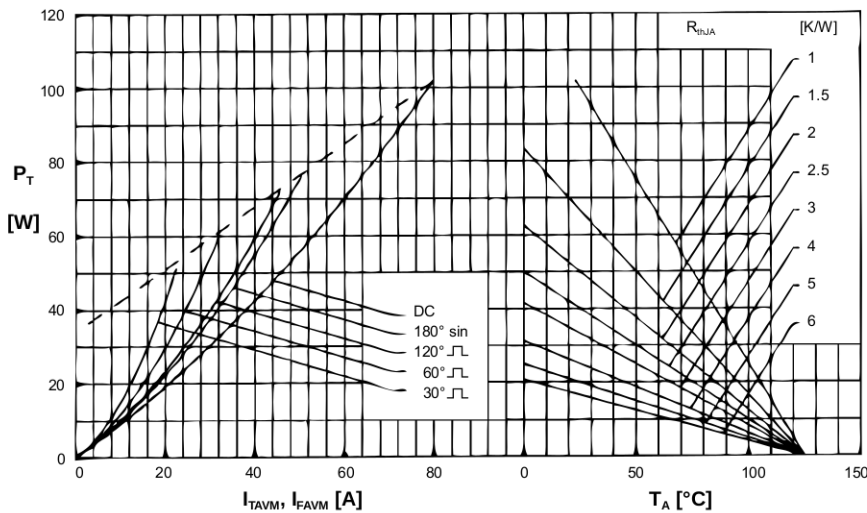


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per thyristor/diode)

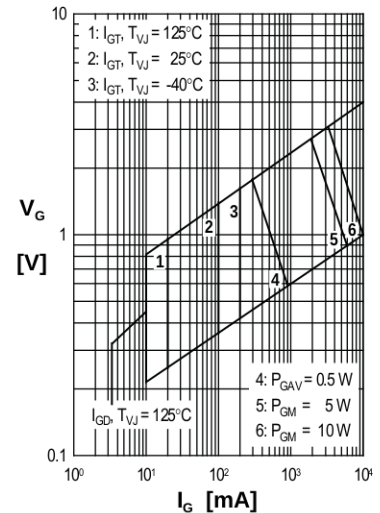


Fig. 5 Gate trigger characteristics

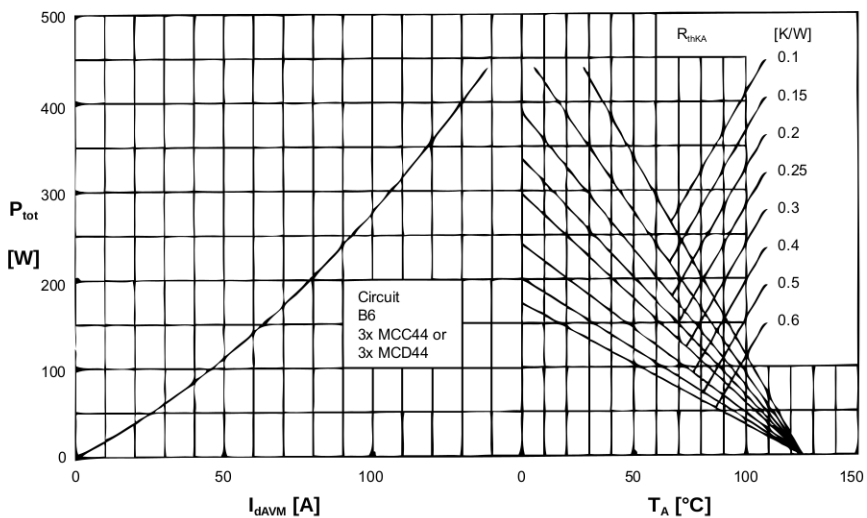


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

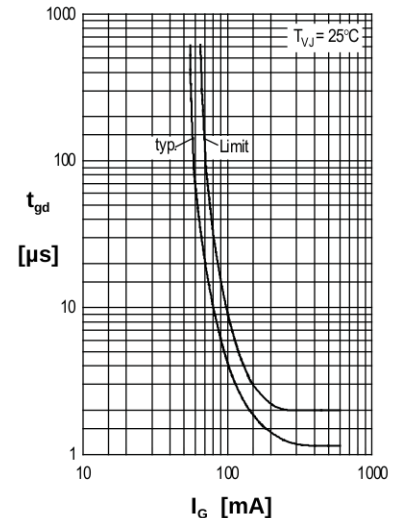


Fig. 7 Gate trigger delay time

Thyristor

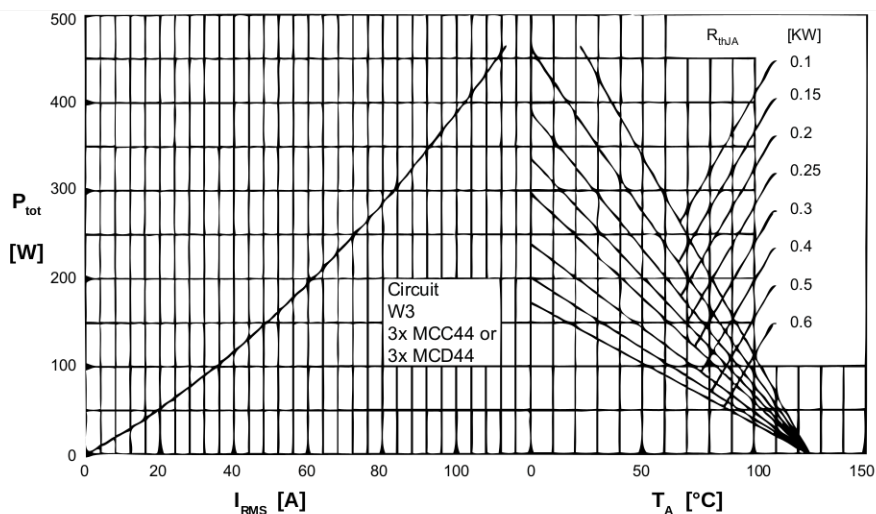


Fig. 8 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

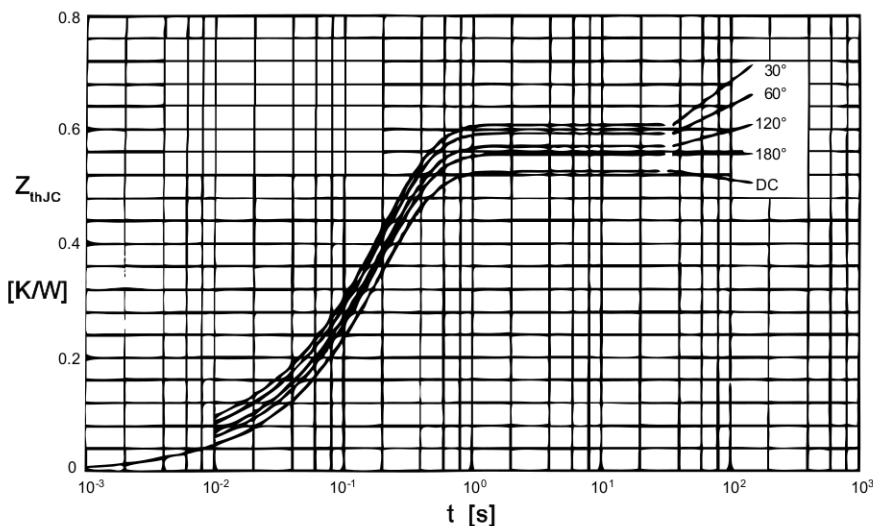


Fig. 9 Transient thermal impedance junction to case (per thyristor)

R_{thJC} for various conduction angles d:

d	R_{thJC} [K/W]
DC	0.53
180°	0.55
120°	0.58
60°	0.60
30°	0.62

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.1950

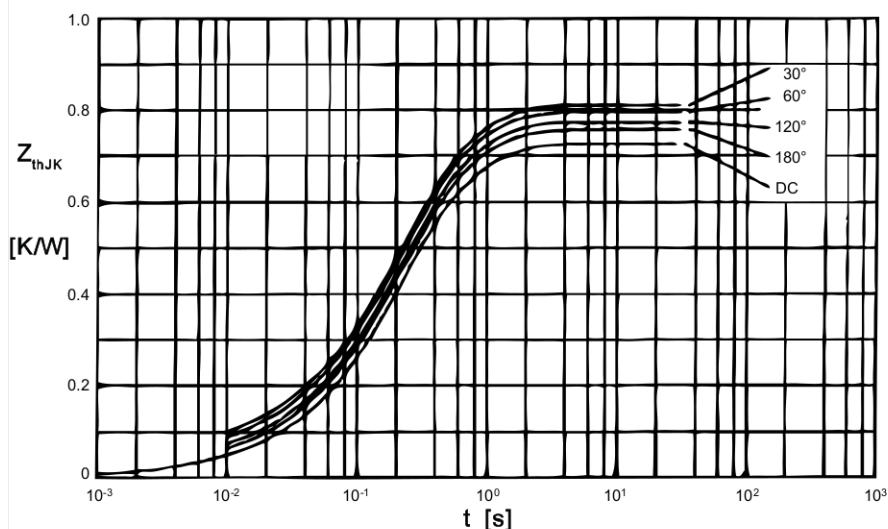


Fig. 10 Transient thermal impedance junction to heatsink (per thyristor)

R_{thJK} for various conduction angles d:

d	R_{thJK} [K/W]
DC	0.73
180°	0.75
120°	0.78
60°	0.80
30°	0.82

Constants for Z_{thJK} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.0195
4	0.200	0.6800